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FSA832 — USB 2.0 High-Speed (480 Mbps) Charger Detection IC with Isolation Switch

Features

USB Detection	USB Battery Charging Rev. 1.2 Supports Data Contact Detect (DCD) Dead Battery Provision (DBP) with 30-Minute Timer
Proprietary Charger and Other Detection	2.7 V / 2.0 V on DP/DM DP/DM Floating PS/2 Port Detection
Switch Type	Isolation Switch Closes for Charging Downstream Port (CDP) Standard Downstream Port (SDP)
V _{BUS}	28 V Over-Voltage Tolerance -2 V Under-Voltage Tolerance
Package	10-Lead MicroPak™ 1.6 x 2.1 mm, 0.5 mm Pitch
Ordering Information	FSA832L10X

Description

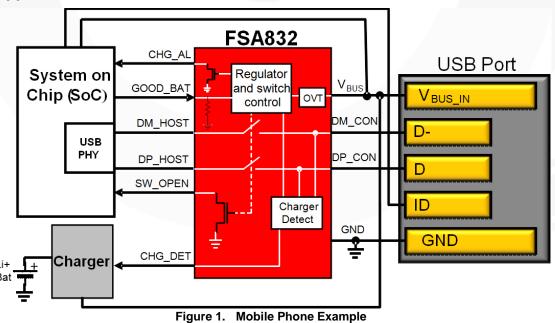
The FSA832 is a charger detection IC with an integrated isolation switch for use with micro/mini USB port. The FSA832 detects USB battery chargers and is compliant with USB Battery Charging Specification, Rev 1.2 (BC1.2).

The FSA832 also detects proprietary chargers that pull the USB data lines HIGH (2.7 V / 2.0 V), floating data lines, and PS/2 ports. The device determines if a charger, either through a Dedicated Charging Port (DCP) or Charging Downstream Port (CDP), is connected or if a typical PC host, a Standard Downstream Port (SDP), is connected. The FSA832 conforms to all the constraints for the Dead Battery Provision (DBP) within the BC1.2 specification, including a 30-minute timer that cannot exceed 45 minutes per BC1.2.

Applications

 MP3, Mobile Internet Device (MID), Cell Phone, PDA, Digital Camera, Notebook, and Netbook

Typical Application



© 2013 Fairchild Semiconductor Corporation FSA832 • Rev. 1.0.1

Ordering Information

Part Number	Operating Temperature Range	Top Mark	5 1	
FSA832L10X	-40 to 85°C	ZY	10-Lead, MicroPak™ 1.6 x 2.1 mm, 0.5 mm Pitch	Tape & Reel

Pin Configurations

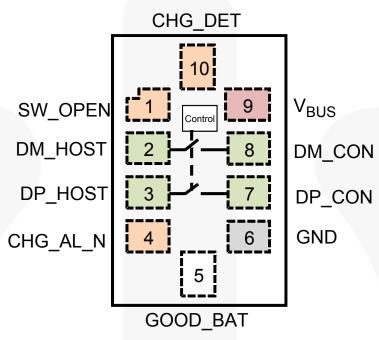


Figure 2. Pin Assignments (Top View)

Pin Descriptions

Name	Pin #	Description
USB Interface		
DP_HOST	3	D+ signal connected to the resident USB transceiver on the phone.
DM_HOST	2	D- signal connected to the resident USB transceiver on the phone.
Connector Interface		
V_{BUS}	9	Input voltage supply pin to be connected to the V _{BUS} pin of the USB connector.
GND	6	Ground
DP_CON	7	Connected to the USB connector D+ pin
DM_CON	8	Connected to the USB connector D- pin
Status Outputs		
CHG_DET	10	CMOS push/pull output connected to charger IC to indicate if a charger has been detected (LOW=charger not detected; HIGH=proprietary charger, DCP, or CDP charger detected).
SW_OPEN	1	Open-drain output pin; requires pull-up resistor to I/O voltage supply (LOW=switch closed; Hi-Z=switch open).
CHG_AL_N	4	CMOS open-drain output pin (LOW= V_{BUS} is valid and charge is allowed to be drawn from V_{BUS} ; Hi-Z= V_{BUS} is not at a valid voltage).
Input Pin		
GOOD_BAT	5	Input that indicates if the battery is a good battery or a dead battery (V_{IL} =dead battery; V_{IH} =good battery).

Note:

1. Output voltage conditions are LOW = V_{OL} and HIGH = V_{OH} .

Table 1. Functionality

Device Detected	GOOD_ BAT	SW_OP EN	CHG_ AL_N	CHG_ DET	DP_HOST	DM_HOST	DP_CON	DM_CON
DCP	Х	Hi-Z	LOW	HIGH	Hi-Z	Hi-Z	V _{DP_SRC} ⁽²⁾	Hi-Z ⁽²⁾
Proprietary Charger	Х	Hi-Z	LOW	HIGH	Hi-Z	Hi-Z	Hi-Z	Hi-Z
CDP	HIGH	LOW	LOW	HIGH	DP_CON	DM_CON	DP_HOST	DM_HOST
CDP	LOW	Hi-Z	LOW	HIGH	Hi-Z	Hi-Z	V_{DP_SRC}	Hi-Z
PS/2 Ports ⁽³⁾	Х	Hi-Z	LOW	LOW	Hi-Z	Hi-Z	Hi-Z	Hi-Z
SDP	HIGH	LOW	LOW	LOW	DP_CON	DM_CON	DP_HOST	DM_HOST
SDP	LOW	Hi-Z	LOW	LOW	Hi-Z	Hi-Z	V _{DP_SRC}	Hi-Z
SDP, CDP, or DCP plugged in and after 30-minute timer expires	LOW	Hi-Z	Hi-Z	LOW	Hi-Z	Hi-Z	Hi-Z	Hi-Z
V _{BUS} < V _{BUS} valid to V _{BUS} > V _{BUS} valid operation prior to completing detection of SDP, CDP, or DCP. Upon detection, all outputs switch as in rows above.	X	Hi-Z	Hi-Z	Hi-Z to LOW	Hi-Z	Hi-Z	Hi-Z	Hi-Z

Note:

- 2. Hi-Z is the internal state of DM_CON. Since a DCP has been detected, DM_CON is shorted to DP_CON externally and DM_CON is shorted to V_{DP_SRC}. V_{DP_SRC} is not put on DP_CON for proprietary chargers.
- DP_CON and DM_CON are pulled to V_{BUS} through a resistor by the PS/2 port when it is connected to the FSA832.

Functional Description

Data Contact Detect (DCD)

DCD relies on the D+ and D- lines being present. DCD waits until the internal timeout $t_{\text{DCD_TOUT}}$ has expired in the following cases:

- If a charger does not have a D+ pin on the USB connector;
- If the D+ pin is not shorted to D- pin on the connector,
- If D+ is pulled up to a supply; or
- If D+ does not have a sufficient path to ground to defeat a pull-up IDP_SRC (IDP_SRC) current source.

The FSA832 proceeds with charger detection even though it is unlikely that a charger is present. If there is no charge, the algorithm reports an SDP and closes the switch. If a device is pulling D+ HIGH, this voltage presents itself to the USB transceiver or Physical Layer Interface (PHY) block within a System on Chip (SoC) after the switch is closed.

If the DCD timeout is insufficient and the PHY block is so equipped, DCD and the charging algorithm can be repeated in the PHY block. The stipulation is that the total time from V_{BUS} valid to USB transceiver connection with a 1.5 k Ω pullup to 3.3 V must be one (1) second, per USB 2.0 standards, provided the portable device does not have a dead battery.

CHG_AL_N Output and Output Timing

CHG_AL_N output indicates that charge is allowed to be drawn from V_{BUS} when CHG_AL_N is LOW. When the FSA832 first powers up and prior to detection, the CHG_AL_N pin can follow V_{BUS} up to 28 V, which is the

absolute maximum V_{BUS} voltage allowed. Whenever V_{BUS} is at GND, the FSA832 is completely off and the switches and all I/Os are in the Hi-Z state. When V_{BUS} climbs above the valid V_{BUS} threshold, detection occurs automatically and CHG_DET, SW_OPEN, and CHG_AL_N all simultaneously switch to the states indicated in Table 1 if GOOD_BAT is HIGH (see Dead Battery Provision description for $GOOD_BAT = LOW$).

Dead Battery Provision

BC1.2 and USB 2.0 allow a portable device (defined as a device with a battery) with a dead battery to take a maximum of 100 mA from the USB V_{BUS} line for a maximum of 45 minutes as long as the portable device forces the D+ line to $V_{\text{DP_SRC}}$. The FSA832 starts detection when V_{BUS} crosses the V_{BUSVLD} threshold and, if it detects a CDP or SDP and GOOD_BAT is HIGH, automatically closes the switch and does not force the DP_CON pin to $V_{\text{DP_SRC}}$.

Once charger detection is complete, the FSA832 starts a 30-minute timer and forces the DP_CON pin to V_{DP_SRC} until the timer elapses. During the 30-minute period; if GOOD_BAT is LOW, V_{DP_SRC} is applied to DP_CON and the D+/D- switches are opened. If GOOD_BAT is HIGH, V_{DP_SRC} is not applied to DP_CON and the D+/D- switches are closed. If GOOD_BAT is LOW when the 30-minute timer expires; regardless of whether a proprietary charger, SDP, CDP, or DCP was previously detected; the FSA832 removes V_{DP_SRC} from DP_CON and forces CHG_DET LOW and CHG_AL_N to Hi-Z (SW_OPEN remains in Hi-Z). To exit this fault condition, remove V_{BUS} , wait for all the V_{BUS} Printed Circuit Board

(PCB) capacitance to discharge, and re-apply V_{BUS} . Table 1 provides the functionality of the pins when the timer expires.

When GOOD_BAT is HIGH and the battery is removed from the portable device while V_{BUS} is valid, bringing GOOD_BAT LOW; the FSA832 opens the isolation switches on DP_CON and DM_CON and forces the DP_CON pin to V_{DP_SRC} . In this scenario, the timer generally expires because the SoC does not have a supply to bring GOOD_BAT HIGH unless the battery that was removed is re-inserted within 30 minutes after the USB plug is inserted.

If an SDP or CDP is inserted with GOOD_BAT HIGH during the 30-minute timer; then GOOD_BAT changes to LOW, SW_OPEN changes to Hi-Z, and the counter continues counting until the 30 minutes expires. If GOOD_BAT then returns to HIGH, SW_OPEN changes to LOW and finishes out the 30-minute time.

GOOD_BAT has an internal pull-down resistor to ensure it is LOW when the SoC is powered down. This input is designed to have very V_{IH} interface with low-voltage SoCs driven with 1.2 V supplies. GOOD_BAT can be connected to the processor supply voltage becauses the processor should wake up whenever V_{BUS} is turned on.

Proprietary Chargers

Chargers pulling the USB data line DM_CON HIGH to 2.0 V or 2.7 V and data line DP_CON HIGH to 2.0 V or 2.7 V are detected by the FSA832 and reported proprietary chargers with a higher charge current allowed. Other chargers that float the DP/DM lines are also detected as a proprietary by means of float detection. This allows a proprietary charger with floating DP/DM to benefit from higher charge current.

PS/2 Port

Mice and keyboards utilizing the PS/2 port interface pull the clock and data pins of the PS/2 connector HIGH to VBUS through a resistive pull-up. When the PS/2 device is adapted to a USB interface, the clock and data pins are translated to the DP_CON and DM_CON lines of the USB connector, respectively.

The benefit of detecting the PS/2 port as a separate device is the ability to limit the current that can be drawn from the bus, thus protecting the PS/2 port. Once the PS/2 port is detected, the DP_HOST and DM_HOST switches remain open to protect the USB PHY connected to DP_HOST and DM_HOST from voltages as high as V_{BUS} .

Ground Drops

When a DCP is detected, V_{DP_SRC} is forced on DP_CON provided GOOD_BAT is HIGH or GOOD_BAT is LOW and the DBP timer has not expired. When ~1.5 A is flowing into V_{BUS} and GND lines of the USB cable, the current can create substantial ground drops that lift the ground of the portable device. This drop adds to the voltage at the DP_CON pin as seen from the DCP D+ pin. For the maximum ground drop of 375 mV specified in the BC1.2 specification and for the maximum V_{DP_SRC} of 0.7 V; the voltage as seen by the DCP would be 1.075 V. Smart DCPs that rely on this voltage detection to determine attach and detach detection need to take this into account.

V_{BUS} Tolerance

When V_{BUS} rises, an internal Power-On Reset (POR) detects this voltage and prepares the FSA832 for charger detection.

 V_{BUS} voltages up to 28 V can be tolerated by the V_{BUS} pin. V_{BUS} can tolerate voltages up to -2 V for cases where a charger is plugged in backwards.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol		Parameter		Min.	Max.	Unit
V _{BUS}	Voltage from USB Conne	oltage from USB Connector				V
V _{SW}	JSB Switch I/O Voltage (DP_CON, DM_CON, DP_HOST, DM_HOST)				6.0	V
I _{SW}	USB Switch Current (DP_	USB Switch Current (DP_CON to DP_HOST, DM_CON to DM_HOST)				mA
V _{I/O}	Voltage from GOOD_BAT	, CHG_AL_N, CHG_DET and SW_OPE	EN I/Os	-0.5	6.0	V
V _{CA}	Voltage from CHG_AL_N Output				28.0	V
I _{I/O}	CHG_AL_N, CHG_DET and SW_OPEN Outputs Sink/Source Current				+5	mA
T _{STG}	Storage Temperature Range				+150	°C
TJ	Maximum Junction Temp	erature			+150	°C
TL	Lead Temperature (Solde	ering, 10 Seconds)			+260	°C
/	IEC 64000 4 2 Cyclero	LICE Ding (DD, CON, DM, CON, V	Air Gap		15	
ECD	IEC 61000-4-2 System	USB Pins (DP_CON, DM_CON, V _{BUS})	Contact		8	14.7
ESD	Human Body Model, JED	an Body Model, JEDEC JESD22-A114			6	kV
	Charged Device Model, J	EDEC JESD22-C101	All Pins		1	

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
V_{BUS}	V _{BUS} Input HIGH Voltage	4	6	V
V_{SW}	Switch I/O Voltage for USB Path	0	3.6	V
T _A	Operating Temperature	-40	+85	°C

DC Electrical Characteristics

Unless otherwise indicated, V_{BUS} =4 V to 6 V and T_A =-40 to +85°C. Typical values are at T_A =25°C unless otherwise specified.

Symbol	Parameter	Condition	Min.	Тур.	Max.	Unit
Status O	utputs					
V _{OHCD}	Output HIGH Voltage (CHG_DET)	I _{OH} =-2 mA	2.0			V
V _{OL}	Output LOW Voltage (CHG_DET, CHG_AL_N, SW_OPEN)	I _{OL} =2 mA			0.4	V
t _{DIFF}	Skew Between Any Output (CHG_DET, CHG_AL_N, SW_OPEN) Switching Relative to Other Outputs Switching	$I_{I/O}$ =±2 mA, CHG_AL_N=20 kΩ to 5 V, SW_OPEN=10 kΩ to 1.8 V			100	ns
V _{BUS} Pin						
VBUS _{VLD}	V _{BUS} Valid Detection Threshold ⁽⁴⁾		8.0		4.0	V
I _{BUSIN}	V _{BUS} Input Leakage	V _{BUS} =0 V to 0.8 V			3	μΑ
I _{VBUSACT}	V _{BUS} Active Mode Average Current	USB Path Active, USB Switch Closed After Charger Detection			250	μΑ
t _{оит}	Time from V _{BUS} Valid Asserted to CHG_DET, CHG_AL_N and SW_OPEN Outputs Valid for BC1.2 Standard Accessory Detection (SDP, DCP, or CDP	DP_CON Pulled Down to GND with 15 kΩ; All Voltages Forced on V _{BUS} , DP_CON, DM_CON, and GND simultaneously			250	ms
Switch C	haracteristics					
I _{OFF}	Power Off Leakage Current	USB Path V _{BUS} =0 V, V _{SW} =0 V or 3.6 V, Figure 4			10	μA
R _{ONUSB}	High-Speed USB Range Switch On Resistance ⁽⁴⁾	V _{DP_CON} / V _{DM_CON} =0 V, 0.4 V; I _{ON} =8 mA; Figure 3; V _{BUS} =4 V to 6 V		4.5	6.0	Ω
Control I	nput			I.		
V _{IH}	Input HIGH Voltage (GOOD_BAT)		1.1			V
VIL	Input LOW Voltage (GOOD_BAT)				0.5	V
R _{PD}	Pull-Down Resistance (GOOD_BAT)		1			ΜΩ
I _{IN}	Input Leakage Current (GOOD_BAT)	V _{BUS} =5 V, GOOD_BAT=0 V to 4.4 V			10	μA
I _{IOFF}	Off-State Leakage Current (GOOD_BAT)	V _{BUS} =0 V, GOOD_BAT=0 V to 4.4 V			10	μA
t _{DBP}	Dead Battery Provision (DBP) Timer		15	30	45	min
$t_{\sf GB}$	Time from GOOD_BAT Asserted to SW_and Meet the R _{ONUSB} Specification	OPEN De-Asserted, Switches Closed			30	ms
t _{DB}	Time from GOOD_BAT De-asserted to S	W_OPEN Asserted, Switches Opened			65	ms
Battery C	harger Detection Parameters from	BC1.2 Specification	I			
V _{DAT_REF}	Data Detect Voltage		0.25		0.40	V
V _{DM_SRC}	D- Source Voltage ⁽⁵⁾		0.5		0.7	V
V _{DP_SRC}	D+ Source Voltage ⁽⁵⁾		0.5		0.7	V
V _{LGC}	Logic Threshold		0.8		2.0	V
I _{DM_SINK}	D- Sink Current		25		175	μA
I _{DP_SINK}	D+ Sink Current		25		175	μA
I _{DP_SRC}	Data Contact Detect Current Source		7		13	μA

Continued on the following page...

DC Electrical Characteristics

Unless otherwise indicated, V_{BUS} =4 V to 6 V and T_A =-40 to +85°C. Typical values are at T_A =25°C unless otherwise specified.

Symbol	Parameter	Condition	Min.	Тур.	Max.	Unit
t _{DCD_DBNC}	Data Contact Detect Debounce		10			ms
t _{DCD_TOUT}	Time for DCD to Timeout		300	450	900	ms
t _{VDPSRC_ON}	D+ Voltage Source On Time		40			ms
t _{VDMSRC_ON}	D- Voltage Source On Time		40			ms

Notes:

- 4. Guaranteed by characterization; not production tested.
- 5. The voltage source, V_{DP_SRC} / V_{DM_SRC}, is able to source at least 250 μA when the output voltage is in the specified range. This voltage source should not pull DP_CON / DM_CON below 2.2 V when DP_CON / DM_CON is pulled to a voltage of 3.0 V minimum or 3.6 V maximum with a resistance of 900 Ω minimum or 1575 Ω maximum.

AC Electrical Characteristics

Unless otherwise specified, values are at T_A=-40 to +85°C; all typical values are for V_{CC}=3.3 V at T_A=25°C.

Symbol	Parameter	Condition	Min.	Тур.	Max.	Unit	Figure
V4-II-	Active Channel Crosstalk, DP COM to	F=1 MHz, RT=50 Ω , C _L =0 pF		-78		-ID	Fig
Xtalk DM_CON ⁽⁶⁾	DM_CON ⁽⁶⁾	F=240 MHz, RT=50 Ω , C _L =0 pF		-36		dB	Figure 6
_	Off Isolation Rejection Ratio,	f=1 MHz, R_T =50 Ω , C_L =0 pF		-84			
O _{IRR}	DM_HOST to DM_CON, DP_HOST to DP_CON ⁽⁶⁾	f=240 MHz, R_T =50 Ω , C_L =0 pF		-34		dB	Figure 5
BW	Bandwidth of Switch ⁽⁶⁾	R _T =50 Ω		1.5		GHz	Figure 5

Note:

6. Guaranteed by characterization; not production tested.

Capacitance

Unless otherwise specified, values are at T_A=-40 to +85°C.

Symbol	Parameter	Condition	Typical	Unit	Figure
C _{OFF}	DP_CON, DM_CON Off Capacitance ⁽⁷⁾	V _{BIAS} =0.2 V, f=1 MHz	3.2	pF	Figure 7
C _{ON}	DP_CON, DM_CON On Capacitance ⁽⁷⁾	V _{BIAS} =0.2 V, f=1 MHz	5.8	pF	Figure 8

Note:

7. Guaranteed by characterization; not production tested.

Network Analyzer

Test Diagrams

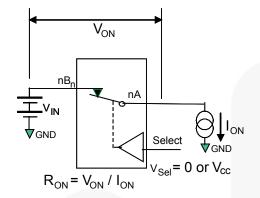
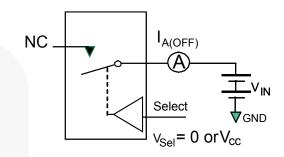
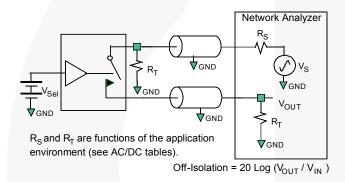


Figure 3. On Resistance



**Each switch port is tested separately.

Figure 4. Off Leakage



 $V_{S1, S2, S3}$ V_{GND} V_{GND} V_{GND} V_{GND} V_{GND} V_{OUT} V_{OUT} V_{GND} V_{GND} V_{OUT} V_{OUT}

Figure 5. Channel Off Isolation

Figure 6. Active Channel Crosstalk

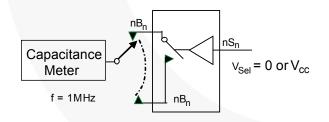


Figure 7. Channel Off Capacitance

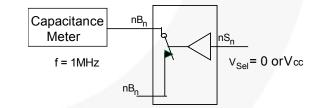
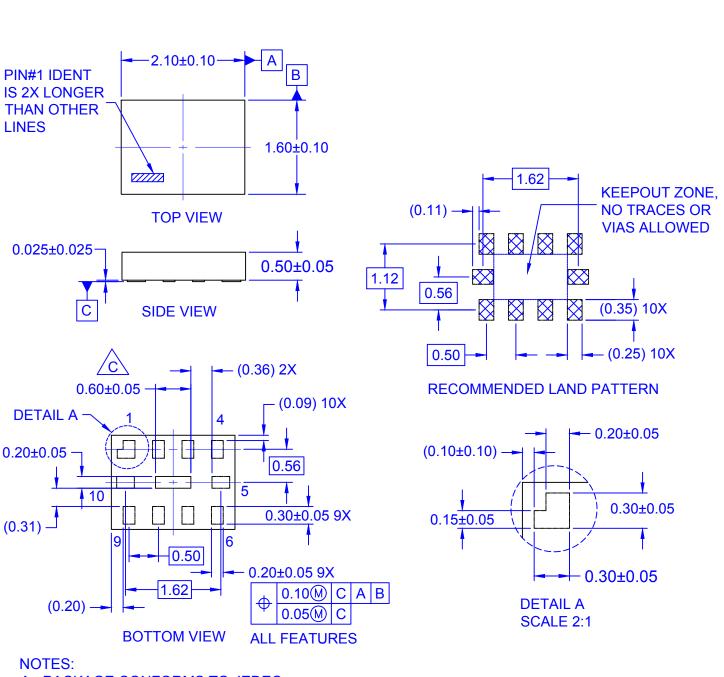


Figure 8. Channel On Capacitance



- A. PACKAGE CONFORMS TO JEDEC REGISTRATION MO-255, VARIATION UABD.
- **B. DIMENSIONS ARE IN MILLIMETERS.**
- PRESENCE OF CENTER PAD IS PACKAGE SUPPLIER DEPENDENT. IF PRESENT IT IS NOT INTENDED TO BE SOLDERED AND HAS A BLACK OXIDE FINISH.
- D. DRAWING FILENAME: MKT-MAC10ArevG.
- E. DIMENSIONS WITHIN () ARE UNCONTROLLED.

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